

View Online at <https://aerobasegroup.com/nsn/5961-00-893-0143>

Inclosure Material:

Metal all transistor

Overall Length:

0.965 inches all transistor

Overall Diameter:

0.625 inches all transistor

Mounting Facility Quantity:

1 all transistor

Internal Configuration:

Junction contact all transistor

Internal Junction Configuration:

Pnp all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

4 transistor

Mounting Method:

Threaded stud all transistor

Features Provided:

Hermetically sealed case and mounting hardware

Overall Width Across Flats:

0.380 inches all transistor

Thread Size:

0.164 inches all transistor

Semiconductor Material:

Germanium all transistor

Voltage Rating In Volts Per Characteristic:

-80.0 collector to base voltage, dc all transistor and -28.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

-3.50 amperes source cutoff current blank all transistor

Maximum Operating Temperature Per Measurement Point:

95.0 degrees celsius junction all transistor

Thread Series Designator:

Unc all transistor

Terminal Type And Quantity:

3 tab, solder lug all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

A110a0